

DATA SHEET



BF494; BF495 NPN medium frequency transistors

Product specification
Supersedes data of September 1994
File under Discrete Semiconductors, SC04

1997 Jul 08

NPN medium frequency transistors

BF494; BF495

FEATURES

- Low current (max. 30 mA)
- Low voltage (max. 20 V).

APPLICATIONS

- HF applications in radio and television receivers
- FM tuners
- Low noise AM mixer-oscillators
- IF amplifiers in AM/FM receivers.

DESCRIPTION

NPN medium frequency transistor in a TO-92; SOT54 plastic package.

PINNING

PIN	DESCRIPTION
1	base
2	emitter
3	collector

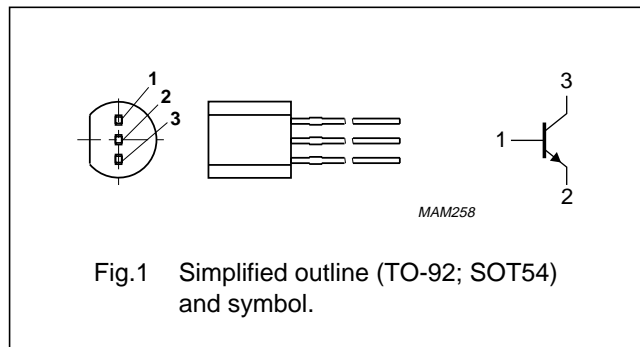


Fig.1 Simplified outline (TO-92; SOT54) and symbol.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter	–	30	V
V_{CEO}	collector-emitter voltage	open base	–	20	V
I_{CM}	peak collector current		–	30	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25\text{ }^\circ\text{C}$	–	300	mW
h_{FE}	DC current gain	$I_C = 1\text{ mA}; V_{CE} = 10\text{ V}$	67	220	
	BF494				
	BF495		35	125	
f_T	transition frequency	$I_C = 1\text{ mA}; V_{CE} = 10\text{ V}; f = 100\text{ MHz}$	120	–	MHz

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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter	–	30	V
V_{CEO}	collector-emitter voltage	open base	–	20	V
V_{EBO}	emitter-base voltage	open collector	–	5	V
I_C	collector current (DC)		–	30	mA
I_{CM}	peak collector current		–	30	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25\text{ °C}$; note 1	–	300	mW
T_{stg}	storage temperature		–65	+150	°C
T_j	junction temperature		–	150	°C
T_{amb}	operating ambient temperature		–65	+150	°C

Note

1. Transistor mounted on an FR4 printed-circuit board.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-a}$	thermal resistance from junction to ambient	note 1	420	K/W

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

$T_{amb} = 25\text{ °C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT	
I_{CBO}	collector cut-off current	$I_E = 0$; $V_{CB} = 20\text{ V}$	–	100	nA	
		$I_E = 0$; $V_{CB} = 20\text{ V}$; $T_{amb} = 150\text{ °C}$	–	4	μA	
I_{EBO}	emitter cut-off current	$I_C = 0$; $V_{EB} = 4\text{ V}$	–	100	nA	
h_{FE}	DC current gain	$I_C = 1\text{ mA}$; $V_{CE} = 10\text{ V}$				
			BF494	67	220	
			BF494B	100	220	
			BF495	35	125	
	BF495B	100	125			
V_{BE}	base-emitter voltage	$I_C = 1\text{ mA}$; $V_{CE} = 10\text{ V}$	650	740	mV	
C_{re}	feedback capacitance	$I_C = 0$; $V_{CB} = 10\text{ V}$; $f = 1\text{ MHz}$	–	1	pF	
f_T	transition frequency	$I_C = 1\text{ mA}$; $V_{CE} = 10\text{ V}$; $f = 100\text{ MHz}$	120	–	MHz	

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PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



DIMENSIONS (mm are the original dimensions)

UNIT	A	b	b ₁	c	D	d	E	e	e ₁	L	L ₁ ⁽¹⁾
mm	5.2 5.0	0.48 0.40	0.66 0.56	0.45 0.40	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE VERSION	REFERENCES			EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ		
SOT54		TO-92	SC-43		97-02-28

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DEFINITIONS

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

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NOTES

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